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Correction: Anomalous red emission with competition and coexistence of defect and band edge emission in photo-electrochemically active (Zn_{0.97}Ga_{0.03})(O_{0.95}N_{0.05}) solid solution

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 Correction for 'Anomalous red emission with competition and coexistence of defect and band edge emission in photo-electrochemically active (Zn_{0.97}Ga_{0.03})(O_{0.95}N_{0.05}) solid solution' by Sumithra Sivadas Menon *et al.*, *RSC Adv.*, 2016, 6, 103081–103087.

The authors wish to clarify two points which were misrepresented in the original manuscript. Firstly, the authors wish to clarify that the valence band shifts upwards, reducing the band gap, and this is due to the repulsion between the hybridized O 2p–N 2p bands and the Zn 3d band.

Secondly, in the original manuscript, the discussion regarding the life time of the trap states omitted the units of the mean harmonic life time of trap states, τ_m . The authors wish to clarify that τ_m is estimated to be 0.16 s.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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